



America Semiconductor

Silicon Bridge Rectifier

2W06M thru
2W10M

$V_{RRM} = 50\text{ V} - 1000\text{ V}$

$I_F = 2\text{ A}$

Features

- Types up to 1000 V V_{RRM}
- Ideal for printed circuit board
- Low forward voltage drop
- High temperature soldering guaranteed: 250°C/ 10 seconds, 0.375" lead length, .5 lbs (2.3kg) tension
- Low leakage current

WOM Package



Mechanical Data

Case: Plastic

Polarity: Color band on body denotes cathode

Mounting position: Any

Terminals: Plated leads, solderable per MIL-STD-202

Method 208 guaranteed

Weight: 1.1 grams

Maximum ratings, at $T_j = 25\text{ }^\circ\text{C}$, unless otherwise specified (2WXXM rectifiers have shorter leads than 2WXXG)

Parameter	Symbol	Conditions	2W06M	2W08M	2W10M	Unit
Repetitive peak reverse voltage	V_{RRM}		600	800	1000	V
RMS reverse voltage	V_{RMS}		420	560	700	V
DC blocking voltage	V_{DC}		600	800	1000	V
Continuous forward current	I_F	$T_C \leq 50\text{ }^\circ\text{C}$	2	2	2	A
Surge non-repetitive forward current, Half Sine Wave	$I_{F,SM}$	$T_C = 25\text{ }^\circ\text{C}$, $t_p = 8.3\text{ ms}$	60	60	60	A
Operating temperature	T_j		-65 to 125	-65 to 125	-65 to 125	$^\circ\text{C}$
Storage temperature	T_{stg}		-65 to 150	-65 to 150	-65 to 150	$^\circ\text{C}$

Electrical characteristics, at $T_j = 25\text{ }^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Conditions	2W06M	2W08M	2W10M	Unit
Diode forward voltage	V_F	$I_F = 2\text{ A}$, $T_j = 25\text{ }^\circ\text{C}$	1.1	1.1	1.1	V
Reverse current	I_R	$V_R = 50\text{ V}$, $T_j = 25\text{ }^\circ\text{C}$	10	10	10	μA
		$V_R = 50\text{ V}$, $T_j = 100\text{ }^\circ\text{C}$	500	500	500	





FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

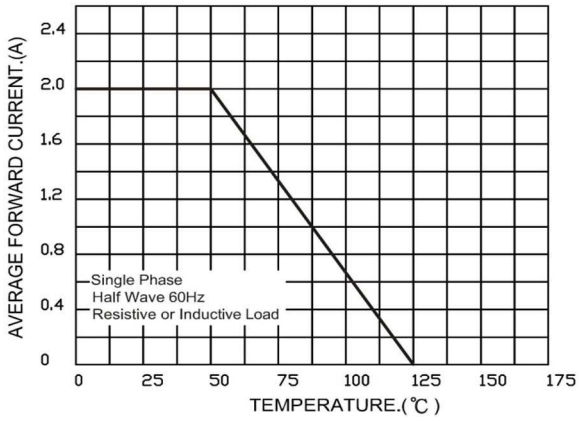


FIG.2-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

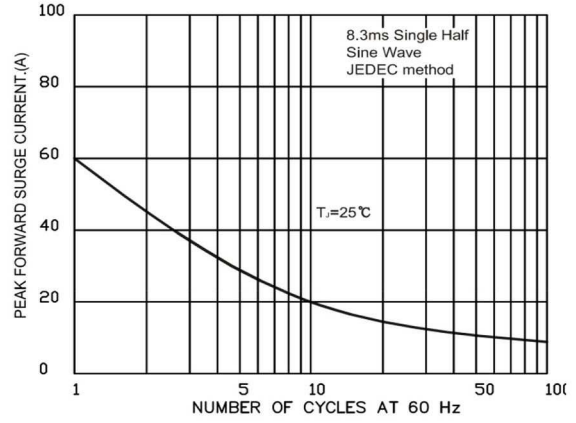


FIG.3-TYPICAL FORWARD CHARACTERISTICS

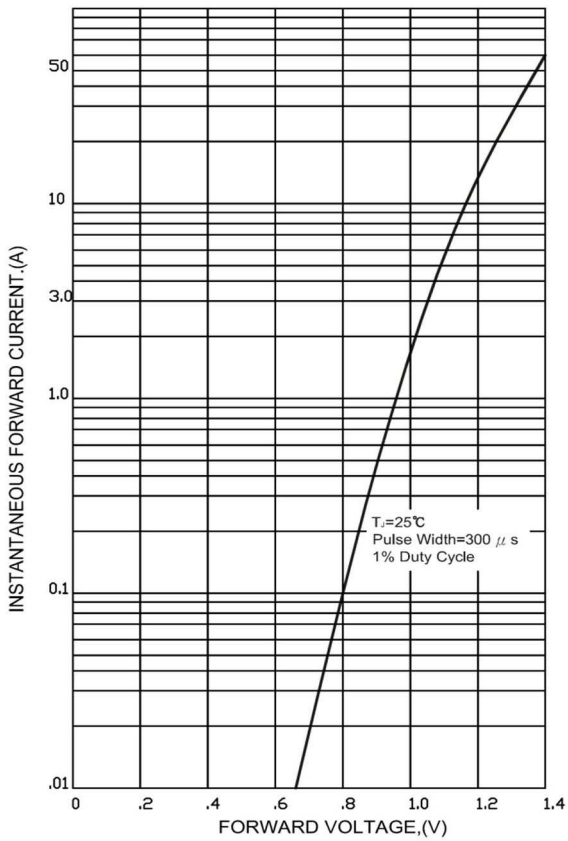


FIG.4-TYPICAL REVERSE CHARACTERISTICS

